

## Features

- High efficiency operation
- Metal silicon junction,majority carrier conduction
- Ultra low forward voltage drop,low power losses
- High forward surge current capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C
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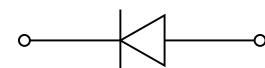
**Reverse Voltage**

20-200 V

**Forward Current**

5 Ampere

## SMBF



## Applications

For use in low voltage high frequency inverters, free wheeling,DC/DC converters, and polarity protection applications.

## Mechanical Data

- Case: SMBF  
Molding compound meets UL 94V-0 flammability rating, RoHS-compliant, halogen-free
- Terminals: Solder plated, solderable per MIL-STD-750,Method 2026
- Polarity: Cathode line denotes the cathode end

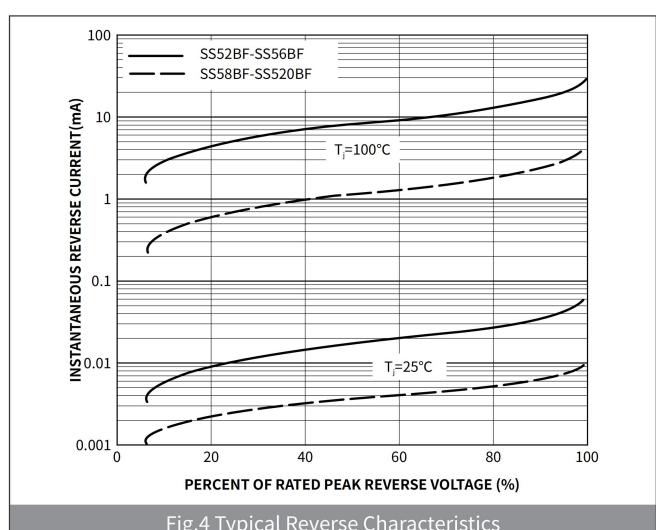
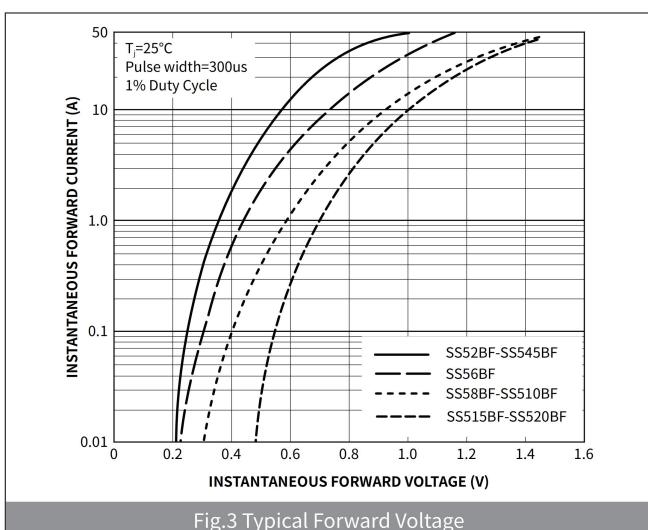
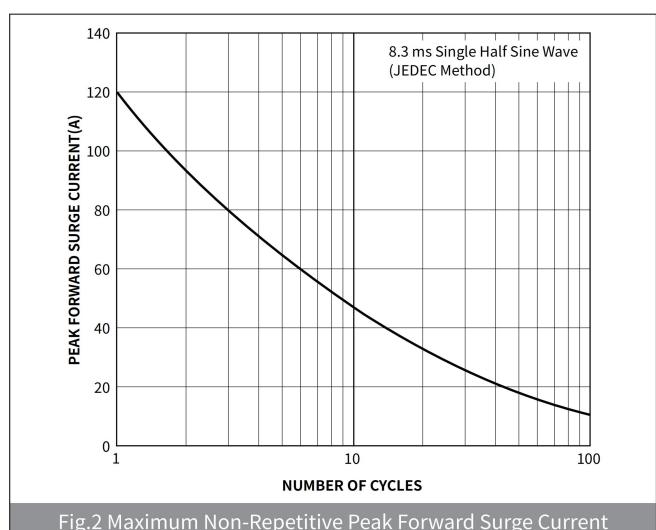
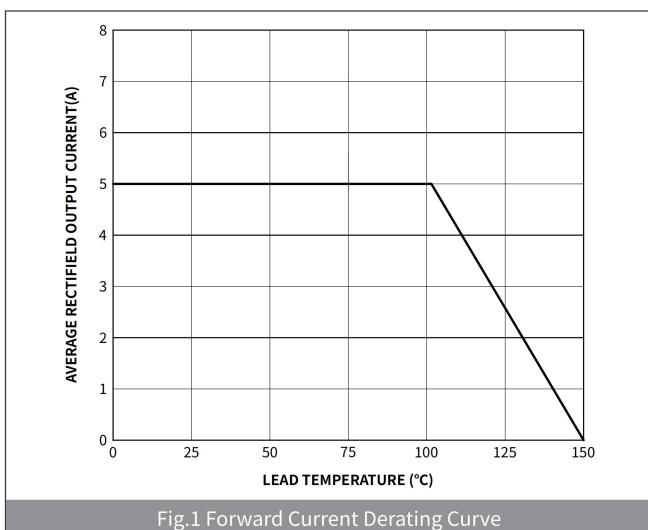
## Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	SS52BF	SS54BF	SS545BF	SS56BF	SS58BF	SS510BF	SS515BF	SS520BF
Device marking code			SS52BF	SS54BF	SS545BF	SS56BF	SS58BF	SS510BF	SS515BF	SS520BF
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	V	20	40	45	60	80	100	150	200
Maximum RMS Voltage	V <sub>RMS</sub>	V	14	28	31.5	42	56	70	105	140
Maximum DC blocking Voltage	V <sub>DC</sub>	V	20	40	45	60	80	100	150	200
Maximum Average Forward Rectified Current @ 60Hz sinewave, Resistance load,TL (Fig.1)	I <sub>F(AV)</sub>	A					5.0			
Non-repetitive Peak Forward Surge Current @ t=8.3ms Half-sine wave	I <sub>FSM</sub>	A					120			
Storage temperature	T <sub>stg</sub>	°C					-55 ~ +150			
Junction temperature	T <sub>j</sub>	°C					-55 ~ +150			
Typical Thermal Resistance	R <sub>θJ-A</sub>	°C /W					78			
	R <sub>θJ-L</sub>	°C /W					20			

**Electrical Characteristics** (Ta=25°C Unless otherwise noted)

PARAMETER	TEST CONDITIONS	SYMBOL	UNIT	SS52BF	SS54BF	SS545BF	SS56BF	SS58BF	SS510BF	SS515BF	SS520BF
Maximum instantaneous forward voltage	I <sub>F</sub> =5.0A	V <sub>F</sub>	V		0.55		0.70		0.85		0.95
Maximum DC reverse current at rated DC blocking voltage	V <sub>R</sub> =V <sub>DC</sub> , T <sub>A</sub> =25°C	I <sub>R1</sub>	mA			0.5			0.05		
	V <sub>R</sub> =V <sub>DC</sub> , T <sub>A</sub> =100°C	I <sub>R2</sub>				50			10		
Typical junction capacitance	4.0V DC,1MHz	C <sub>J</sub>	pF		800			500			

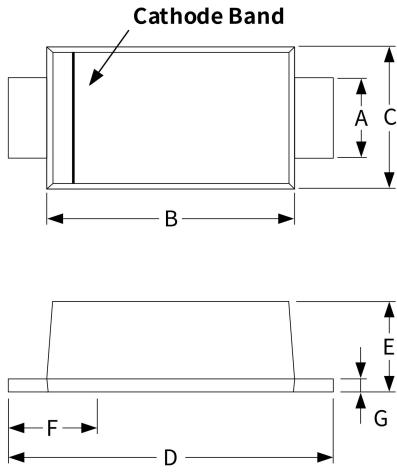
**Ratings And Characteristics Curves** (Ta=25°C Unless otherwise specified)



### Ordering Information

PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SMBF	R2	0.065	3000	6000	48000	11"
SMBF	R3	0.065	5000	10000	80000	13"

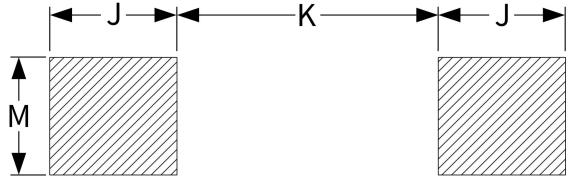
### Package Outline Dimensions (SMBF)



**Cathode Band**

Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	1.90	2.10	0.074	0.083
B	4.15	4.45	0.163	0.175
C	3.40	3.80	0.133	0.150
D	5.10	5.60	0.200	0.220
E	1.05	1.55	0.041	0.061
F	0.70	1.35	0.027	0.053
G	0.15	0.25	0.006	0.010

### Suggested Pad Layout



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
M	2.20	-	0.086	-
J	1.90	-	0.075	-
K	-	2.40	-	0.094